

HD74AC74

Dual D-Type Positive Edge-Triggered Flip-Flop

REJ03D0277-0200Z (Previous ADE-205-361 (Z)) Rev.2.00 Jul.16.2004

Description

The HD74AC74 is a dual D-type flip-flop with Asynchronous Clear and Set inputs and complementary (Q, \overline{Q}) outputs. Information at the input is transferred to the outputs on the positive edge of the clock pulse. Clock triggering occurs at a voltage level of the clock pulse and is not directly related to the transition time of the positive-going pulse. After the Clock Pulse input threshold voltage has been passed, the Data input is locked out and information present will not be transferred to the outputs until the next rising edge of the Clock Pulse input.

Features

Asynchronous Inputs:

Low input to \overline{S}_D (Set) sets Q to High level Low input to \overline{C}_D (Clear) sets Q to Low level Clear and Set are independent of clock Simultaneous Low on \overline{C}_D and \overline{S}_D makes both Q and \overline{Q} High

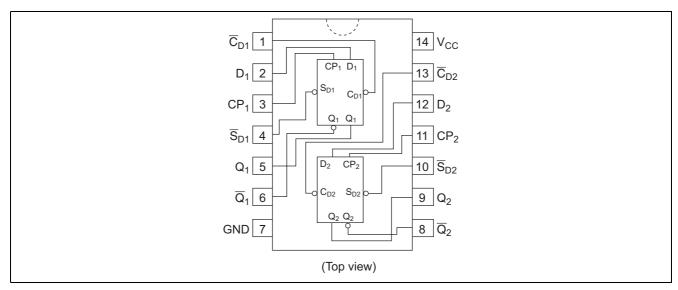
- Outputs Source/Sink 24 mA
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74AC74P	DIP-14 pin	DP-14, -14AV	Р	_
HD74AC74FPEL	SOP-14 pin (JEITA)	FP-14DAV	FP	EL (2,000 pcs/reel)
HD74AC74RPEL	SOP-14 pin (JEDEC)	FP-14DNV	RP	EL (2,500 pcs/reel)
HD74AC74TELL	TSSOP-14 pin	TTP-14DV	Т	ELL (2,000 pcs/reel)

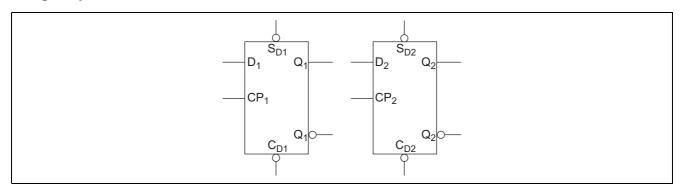
Notes: 1. Please consult the sales office for the above package availability.

2. The packages with lead-free pins are distinguished from the conventional products by adding V at the end of the package code.

Pin Arrangement



Logic Symbol



Pin Names

 $\begin{array}{lll} D_1, D_2 & Data \ Inputs \\ CP_1, CP_2 & Clock \ Pulse \ Inputs \\ \overline{C}_{D1}, \overline{C}_{D2} & Direct \ Clear \ Inputs \\ \overline{S}_{D1}, \overline{S}_{D2} & Direct \ Set \ Inputs \\ Q_1, \overline{Q}_1, Q_2, \overline{Q}_2 & Outputs \end{array}$

Truth Table (Each Half)

Inputs				Outputs	
S _D	<u>C</u> _D	СР	D	Q	Q
L	Н	Х	Х	Н	L
Н	L	Х	Х	L	Н
L	L	X	X	Н	H
Н	Н		Н	Н	L
Н	Н		L	L	Н
Н	Н	L	Х	Q_0	Q_0

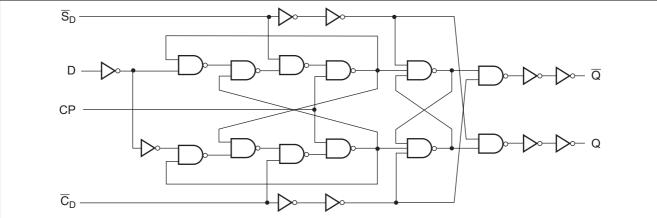
H : High Voltage Level
L : Low Voltage Level

X : Immaterial

 $oldsymbol{\bot}$: Low-to-High Clock Transition

 $Q_0(\overline{Q}_0)$: Previous $Q(\overline{Q})$ before Low-to-High Transition of Clock

Logic Diagram



Please note that this diagram is provised only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Condition
Supply voltage	V _{cc}	-0.5 to 7	V	
DC input diode current	I _{IK}	-20	mA	$V_1 = -0.5V$
		20	mA	$V_1 = Vcc+0.5V$
DC input voltage	V _I	-0.5 to Vcc+0.5	V	
DC output diode current	I _{ok}	-50	mA	$V_0 = -0.5V$
		50	mA	$V_O = Vcc+0.5V$
DC output voltage	V _o	-0.5 to Vcc+0.5	V	
DC output source or sink current	Io	±50	mA	
DC V _{CC} or ground current per output pin	I _{CC} , I _{GND}	±50	mA	
Storage temperature	Tstg	-65 to +150	°C	

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Condition
Supply voltage	V _{cc}	2 to 6	V	
Input and output voltage	V_{I}, V_{O}	0 to V _{CC}	V	
Operating temperature	Та	-40 to +85	°C	
Input rise and fall time	tr, tf	8	ns/V	$V_{CC} = 3.0V$
(except Schmitt inputs)				V _{CC} = 4.5 V
V _{IN} 30% to 70% V _{CC}				V _{CC} = 5.5 V

DC Characteristics

Item	Sym- bol	Vcc (V)	7	Га = 25°(C	Ta = -40 to +85°C		Unit	Condition
			min.	typ.	max.	min.	max.		
Input Voltage	V _{IH}	3.0	2.1	1.5	_	2.1	_	V	$V_{OUT} = 0.1 \text{ V or } V_{CC} - 0.1 \text{ V}$
		4.5	3.15	2.25	—	3.15	—		
		5.5	3.85	2.75	—	3.85	—		
	V_{IL}	3.0	_	1.50	0.9	_	0.9		$V_{OUT} = 0.1 \text{ V or } V_{CC} - 0.1 \text{ V}$
		4.5	_	2.25	1.35	_	1.35		
		5.5	_	2.75	1.65	_	1.65		
Output voltage	V _{OH}	3.0	2.9	2.99	_	2.9	_	٧	$V_{IN} = V_{IL} \text{ or } V_{IH}$
		4.5	4.4	4.49	_	4.4	_		$I_{OUT} = -50 \mu A$
		5.5	5.4	5.49	_	5.4	_		
		3.0	2.58	_	_	2.48	_		$V_{IN} = V_{IL} \text{ or } V_{IH}$ $I_{OH} = -12 \text{ mA}$
		4.5	3.94	_	_	3.80	_		$I_{OH} = -24 \text{ mA}$
		5.5	4.94	_	_	4.80	_		$I_{OH} = -24 \text{ mA}$
	V _{OL}	3.0	_	0.002	0.1	_	0.1		$V_{IN} = V_{IL} \text{ or } V_{IH}$
		4.5	_	0.001	0.1	_	0.1		I _{OUT} = 50 μA
		5.5	_	0.001	0.1	_	0.1		
		3.0	_	_	0.32	_	0.37		$V_{IN} = V_{IL} \text{ or } V_{IH}$ $I_{OL} = 12 \text{ mA}$
		4.5	_	_	0.32	_	0.37		$I_{OL} = 24 \text{ mA}$
		5.5	_	_	0.32	_	0.37		$I_{OL} = 24 \text{ mA}$
Input leakage current	I _{IN}	5.5	_	_	±0.1	_	±1.0	μА	$V_{IN} = V_{CC}$ or GND
Dynamic output	I _{OLD}	5.5	_	_	_	86	_	mΑ	V _{OLD} = 1.1 V
current*	I _{OHD}	5.5	_	_	_	-75	_	mΑ	V _{OHD} = 3.85 V
Quiescent supply current	I _{cc}	5.5	_	_	4.0	_	40	μА	$V_{IN} = V_{CC}$ or ground

^{*}Maximum test duration 2.0 ms, one output loaded at a time.



AC Characteristics

			Ta = +25°C C _L = 50 pF				C to +85°C 50 pF	
Item	Symbol	V _{cc} (V)*1	Min	Тур	Max	Min	Max	Unit
Maximum clock	f _{max}	3.3	100	125	_	95	_	MHz
frequency		5.0	140	160	_	125	_	
Propagation delay	t _{PLH}	3.3	1.0	8.0	12.0	1.0	13.0	ns
\overline{C}_{Dn} or \overline{S}_{Dn} to Q_n or Q_n		5.0	1.0	6.0	9.0	1.0	10.0	
Propagation delay	t _{PHL}	3.3	1.0	10.5	12.0	1.0	13.5	ns
\overline{C}_{Dn} or \overline{S}_{Dn} to Q_n or Q_n		5.0	1.0	8.0	9.5	1.0	10.5	
Propagation delay	t _{PLH}	3.3	1.0	8.0	13.5	1.0	16.0	ns
CP _n to Q _n or Q _n		5.0	1.0	6.0	10.0	1.0	10.5	
Propagation delay	t _{PHL}	3.3	1.0	8.0	14.0	1.0	14.5	ns
CP _n to Q _n or Q _n		5.0	1.0	6.0	10.0	1.0	10.5	

Note: 1. Voltage Range 3.3 is $3.3 \text{ V} \pm 0.3 \text{ V}$ Voltage Range 5.0 is $5.0 \text{ V} \pm 0.5 \text{ V}$

AC Operating Requirements

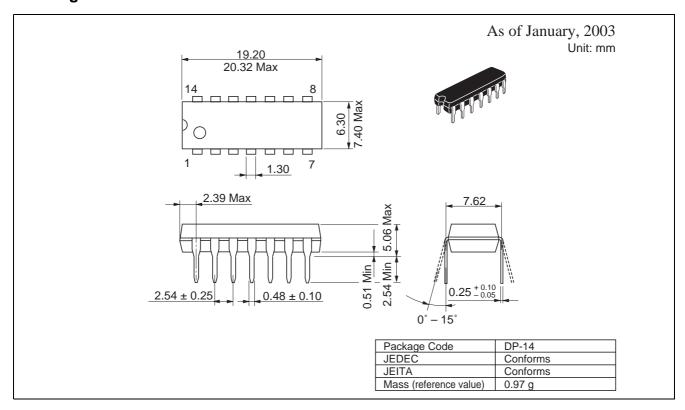
			Ta = +25°C C _∟ = 50 pF		Ta = -40°C to +85°C C _L = 50 pF	
Item	Symbol	V _{cc} (V)*1	Тур	Guarantee	d Minimum	Unit
Set-up time, HIGH or LOW	t _{su}	3.3	1.5	4.0	4.5	ns
D _n to CP _n		5.0	1.0	3.0	3.0	
Hold time, HIGH or LOW	t _h	3.3	-2.0	0	0	ns
D _n to CP _n		5.0	-1.5	0	0	
CP_n or \overline{C}_{Dn} or \overline{S}_{Dn}	t _w	3.3	3.0	5.5	7.0	ns
Pulse width		5.0	2.5	4.5	5.0	
Recovery time	t _{rec}	3.3	-2.5	0	0	ns
\overline{C}_{Dn} or \overline{S}_{Dn} to CP		5.0	-2.0	0	0	

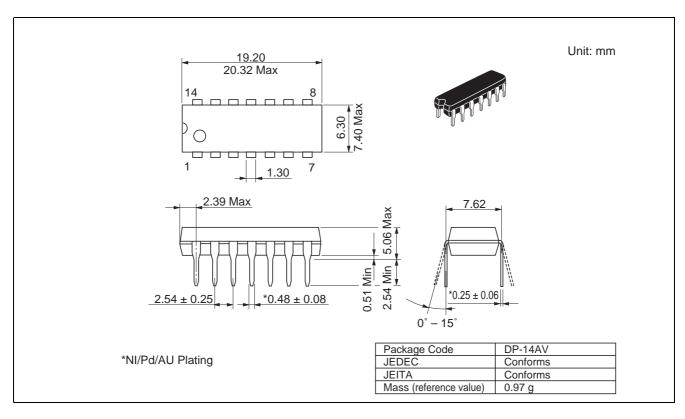
Note: 1. Voltage Range 3.3 is 3.3 V \pm 0.3 V Voltage Range 5.0 is 5.0 V \pm 0.5 V

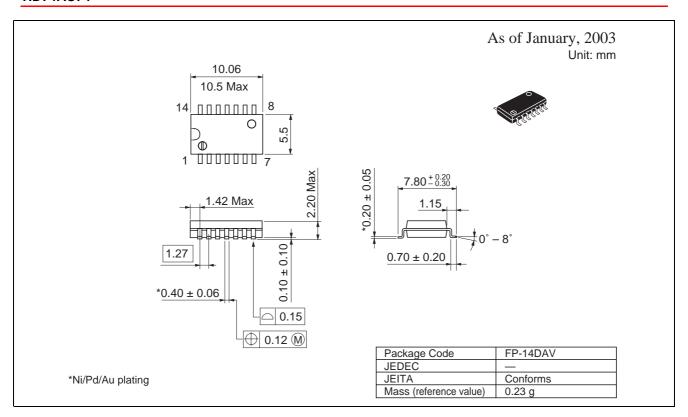
Capacitance

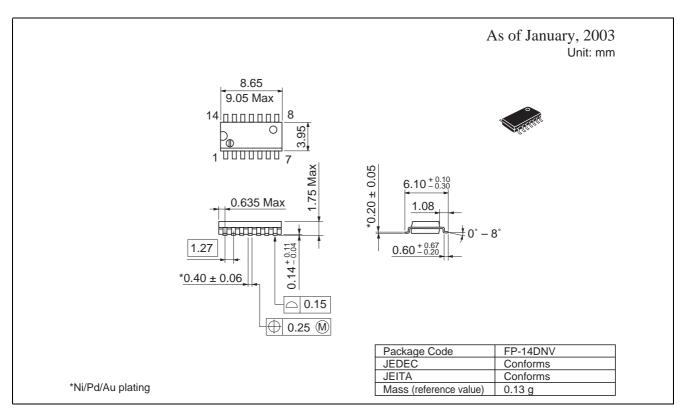
Item	Symbol	Тур	Unit	Condition
Input capacitance	C _{IN}	4.5	pF	$V_{CC} = 5.5 \text{ V}$
Power dissipation capacitance	C_{PD}	35.0	pF	$V_{CC} = 5.0 \text{ V}$

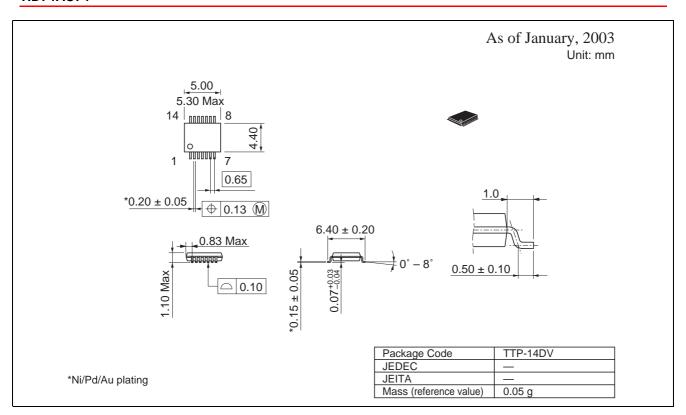
Package Dimensions











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